



Intersubband Absorption Loss for 10.3μm Quantum Cascade Lasers



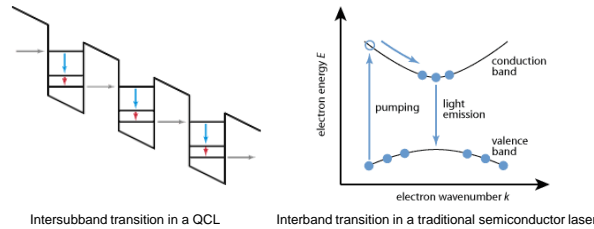
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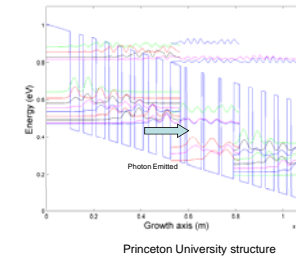
Background

- QCL's are semiconductor devices that emit light in the mid to far infrared
- They emit multiple photons per electron, as opposed to traditional lasers which emit only one photon per electron, for each trip through the device
- Electrons make intersubband transitions, as opposed to interband transitions

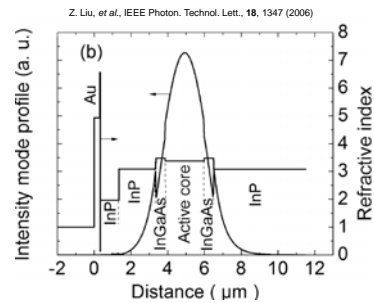
Intersubband vs. Interband Transitions



10.3μm QCL Design



QCL Diagram



Sources of Loss

Intersubband Absorption

For one transition:

$$\alpha_{\text{issb}}(\omega) = \frac{4\pi e^2 \pi n_{2D} \langle z_{ij} \rangle^2}{\epsilon_0 n 2L_p \lambda_{ij}} \frac{\gamma_{ij}/\pi}{(E_{ij} - \hbar\omega)^2 + \gamma_{ij}^2}$$

For the entire device:

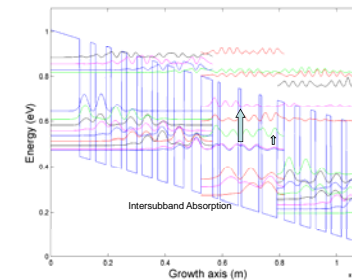
$$\alpha_{\text{issb}}(\omega) = \frac{4\pi e^2 \pi n_{2D} \sum_j \langle z_{ij} \rangle^2}{\epsilon_0 n 2L_p \lambda_{ij}} \frac{\gamma_{ij}/\pi}{(E_{ij} - \hbar\omega)^2 + \gamma_{ij}^2}$$

Free carrier absorption in the waveguide

$$\alpha_{fc} \sim \frac{N_c e^2 \gamma}{\eta_0 m_c \omega^2}$$

As energy increases, free carrier absorption gets less significant relative to the off-resonant intersubband absorption

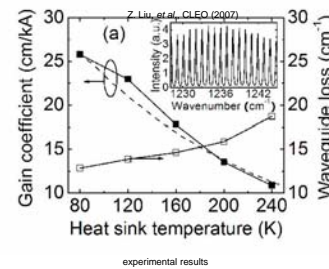
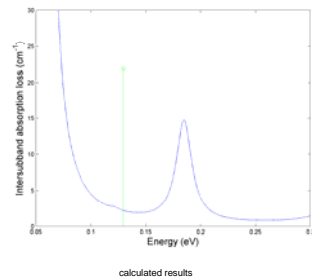
Loss in Diagram



The Shooting Method

- Computational method used to solve wave equations
- Reduces boundary value problems into initial value problems
- Used to "shoot" electrons and look for resonance in wave equations

Results



Conclusions

- Loss in the active region is an important performance parameter
- It is crucial to design the laser active region to avoid gain/loss overlap.
- Experimental results and calculated results are similar, but not completely
- Future work: optimizing the model

